$v_{\rm F} = 0.57$ V at $I_{\rm F} = 2.5$ A

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C

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 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals:mattentinplatedleads,solderableperJ-STD-002andJESD22-B102E3 and M3 suffix meet JESD 201 class 2 whisker test

-40 to +175

Polarity: as marked

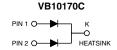
MAXIMUM RATINGS (T_A = 25 °C unless otherwise noted) PARAMETER SYMBOL VB10170C UNIT Maximum repetitive peak reverse voltage V_{RRM} 170 V per device 10 Maximum average forward rectified current А I_{F(AV)} (fig. 1) 5 per diode Peak forward surge current 8.3 ms single half sine-wave 80 А I_{FSM} superimposed on rated load 10 000 Voltage rate of change (rated V_R) dV/dt V/µs

T_J, T_{STG}

Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.57$ V at $I_F = 2.5$ A

TMBS® D²PAK (TO-263AB)



LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | |
|--|-------------------------------|--|--|
| I _{F(AV)} | 2 x 5 A | | |
| V _{RRM} | 170 V | | |
| I _{FSM} | 80 A | | |
| V _F at I _F = 5.0 A | 0.65 V | | |
| T _J max. | 175 °C | | |
| Package | D ² PAK (TO-263AB) | | |
| Circuit configuration | Common cathode | | |

Operating junction and storage temperature range

Revision: 23-Feb-2024



VB10170C

RoHS COMPLIANT HALOGEN

°C





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| ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted) | | | | | | |
|---|-------------------------|---------------------------|-------------------------------|------|------|------|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT |
| Instantaneous forward voltage per diode | I _F = 2.5 A | T _A = 25 °C | V _F ⁽¹⁾ | 0.74 | - | V |
| | $I_{F} = 5.0 \text{ A}$ | | | 0.84 | 1.03 | |
| | I _F = 2.5 A | - T _A = 125 °C | | 0.57 | - | |
| | I _F = 5.0 A | | | 0.65 | 0.74 | |
| Reverse current per diode | V _R = 136 V | T _A = 25 °C | I _R ⁽²⁾ | 0.3 | - | μA |
| | | T _A = 125 °C | | 0.9 | - | mA |
| | $V_{-} = 170 V_{-}$ | T _A = 25 °C | | - | 90 | μA |
| | V _R = 170 V | T _A = 125 °C | | 1.3 | 10 | mA |

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

| THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | |
|--|------------|-----------------------|----------|------|--|
| PARAMETER | | SYMBOL | VB10170C | UNIT | |
| Typical thermal resistance | per diode | $R_{	extsf{	heta}JC}$ | 3.0 | °C/W | |
| | per device | | 1.7 | | |

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|----------------|-----------------|--------------|---------------|---------------|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | |
| D ² PAK (TO-263AB) | VB10170C-E3/4W | 1.38 | 4W | 50/tube | Tube | |
| D ² PAK (TO-263AB) | VB10170C-E3/8W | 1.38 | 8W | 800/reel | Tape and reel | |
| D ² PAK (TO-263AB) | VB10170C-M3/I | 1.38 | I | 800/reel | Tape and reel | |

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

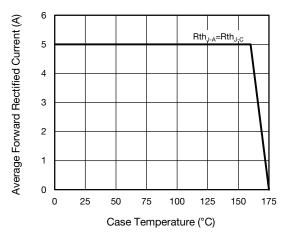


Fig. 1 - Maximum Forward Current Derating Curve

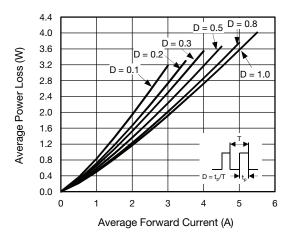
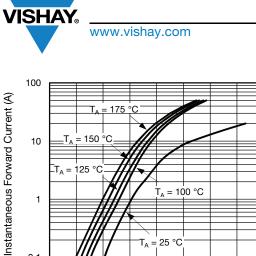


Fig. 2 - Forward Power Loss Characteristics Per Diode

VB10170C





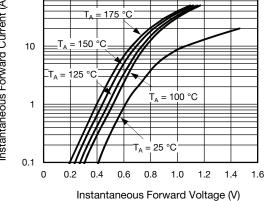


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

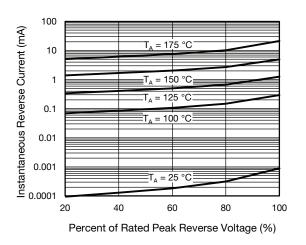
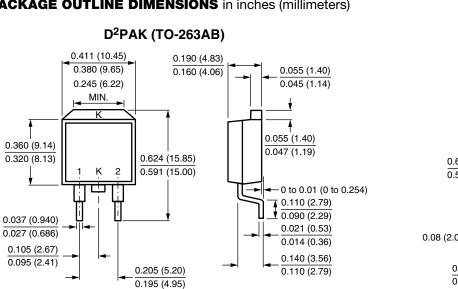
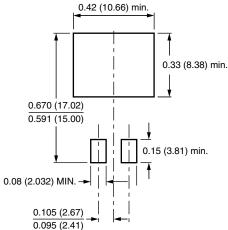


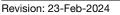
Fig. 4 - Typical Reverse Characteristics Per Diode





Mounting Pad Layout

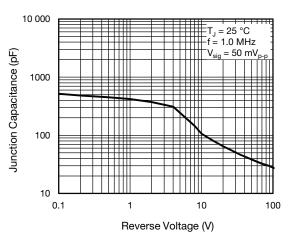


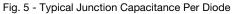


3

Document Number: 89948

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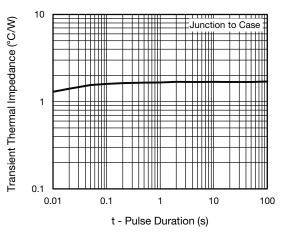


Fig. 6 - Typical Transient Thermal Impedance Per Diode



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1